



## 超快恢复整流二极管 Ultra-Fast Recovery Rectifier Diodes

## ■ 特征 Features

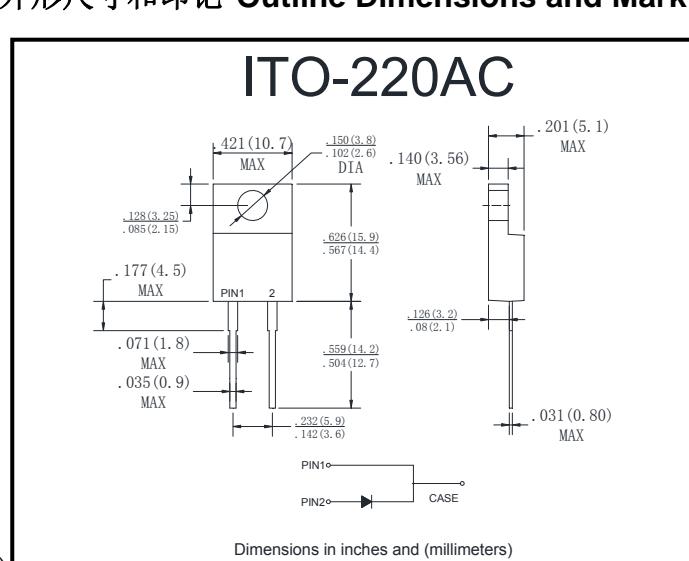
- $I_o$  8.0A
- $V_{RRM}$  100V~600V
- 玻璃钝化芯片 Glass passivated chip
- 耐正向浪涌电流能力高  
High surge forward current capability

## ■ 用途 Applications

- 快速整流用  
High speed switching

## ■ 极限值 (绝对最大额定值)

## Limiting Values (Absolute Maximum Rating)



参数名称 Item	符号 Symbol	单位 Unit	测试条件 Conditions	MUR				
				810F	815F	820F	840F	860F
反向重复峰值电压 Repetitive Peak Reverse Voltage	$V_{RRM}$	V		100	150	200	400	600
平均整流输出电流 Average Rectified Output Current	$I_o$	A	正弦半波 60Hz, 电阻负载, $T_c$ (Fig.1) 60Hz Half-sine wave, Resistance load, $T_c$ (Fig.1)					8
正向(不重复)浪涌电流 Surge(Non-repetitive)Forward Current	$I_{FSM}$	A	60Hz正弦波, 一个周期, $T_a=25^\circ C$ 60Hz sine wave, 1 cycle, $T_a=25^\circ C$					125
正向浪涌电流的平方对电流浪涌持续时间的积分值 Current Squared Time	$I^2t$	$A^2s$	$1ms \leq t \leq 8.3ms$ $T_j=25^\circ C$					65
贮存温度 Storage Temperature	$T_{stg}$	$^\circ C$						-55 ~ +150
结温 Junction Temperature	$T_j$	$^\circ C$						-55 ~ +150

■ 电特性 ( $T_a=25^\circ C$  除非另有规定)Electrical Characteristics ( $T_a=25^\circ C$  Unless otherwise specified)

参数名称 Item	符号 Symbol	单位 Unit	测试条件 Test Condition	MUR				
				810F	815F	820F	840F	860F
正向峰值电压 Peak Forward Voltage	$V_{FM}$	V	$I_{FM}=8.0A$		0.95		1.25	1.7
反向峰值电流 Peak Reverse Current	$I_{RRM1}$	$\mu A$	$V_{RM}=V_{RRM}$	$T_a=25^\circ C$				10
	$I_{RRM2}$			$T_a=125^\circ C$				500
反向恢复时间 Reverse Recovery Time	$T_{rr}$	ns	$I_F=0.5A$ $I_{RM}=1A$ $I_{RR}=0.25A$		35		50	
热阻 Thermal Resistance	$R_{\theta J-C}$	$^\circ C/W$	结和壳之间 Between junction and case				2.0	



## ■特性曲线(典型) Characteristics(Typical)

图1: 正向电流降额曲线

FIG1:Forward Current Derating Curve

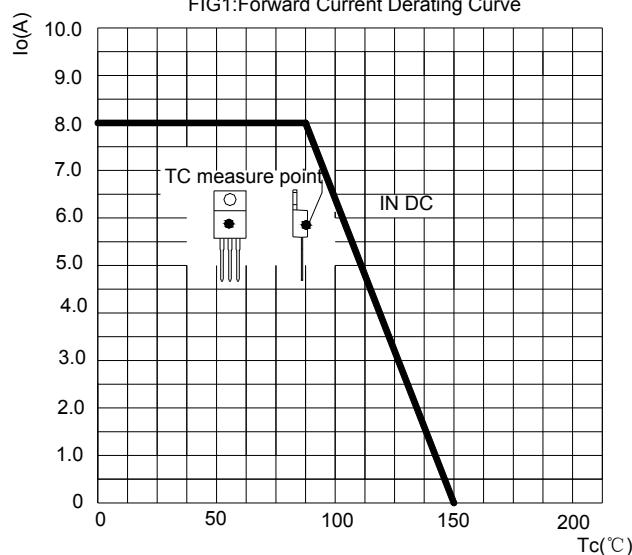


图2: 耐正向浪涌电流曲线

FIG2:Surge Forward Current Capability

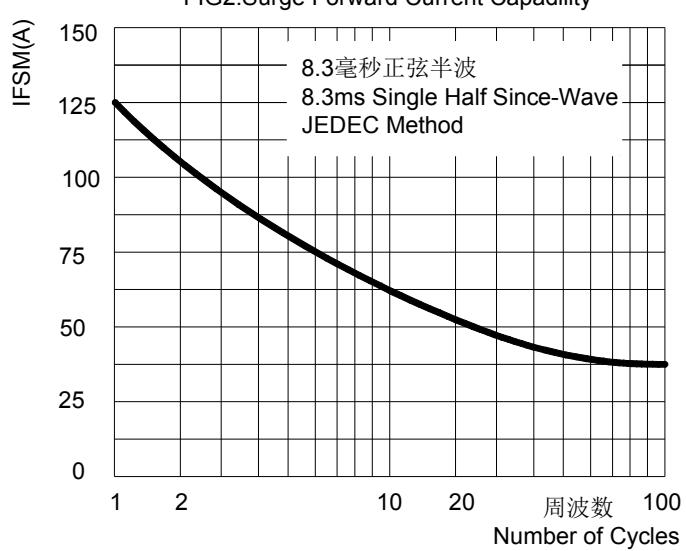


图3: 正向电压曲线

FIG3:Instantaneous Forward Voltage

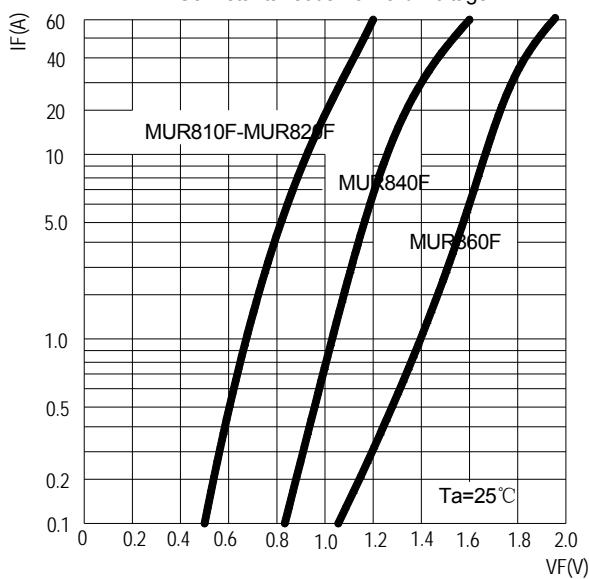


图4: 反向电流曲线

FIG4:Typical Reverse Characteristics

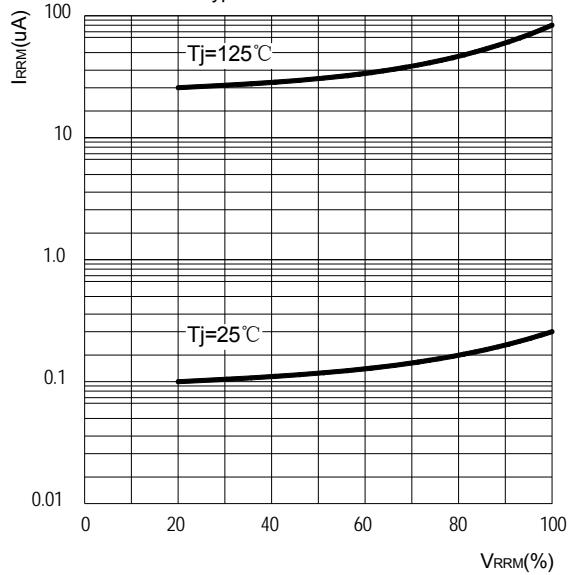


图5: 反向恢复时间试验电路及测试波形示意图  
Diagram of circuit and Testing wave form of reverse recovery time

